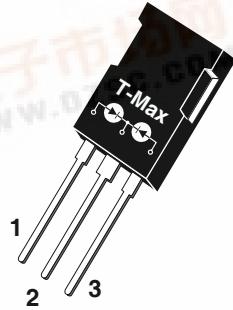
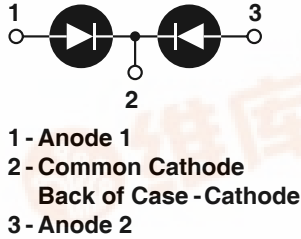


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**APT60S20B2CT 200V 2X75A**

## HIGH VOLTAGE SCHOTTKY DIODE

PRODUCT APPLICATIONS	PRODUCT FEATURES	PRODUCT BENEFITS
<ul style="list-style-type: none"> <li>• Parallel Diode                             <ul style="list-style-type: none"> <li>-Switchmode Power Supply</li> <li>-Inverters</li> </ul> </li> <li>• Free Wheeling Diode                             <ul style="list-style-type: none"> <li>-Motor Controllers</li> <li>-Converters</li> </ul> </li> <li>• Snubber Diode</li> <li>• Uninterruptible Power Supply (UPS)</li> <li>• 48 Volt Output Rectifiers</li> <li>• High Speed Rectifiers</li> </ul>	<ul style="list-style-type: none"> <li>• Ultrafast Recovery Times</li> <li>• Soft Recovery Characteristics</li> <li>• Popular T-MAX™ Package</li> <li>• Low Forward Voltage</li> <li>• High Blocking Voltage</li> <li>• Low Leakage Current</li> </ul>	<ul style="list-style-type: none"> <li>• Low Losses</li> <li>• Low Noise Switching</li> <li>• Cooler Operation</li> <li>• Higher Reliability Systems</li> <li>• Increased System Power Density</li> </ul>

### MAXIMUM RATINGS

All Ratings Are Per Leg:  $T_C = 25^\circ\text{C}$  unless otherwise specified.

Symbol	Characteristic / Test Conditions	APT60S20B2CT	UNIT
$V_R$	Maximum D.C. Reverse Voltage	200	Volts
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage		
$V_{RWM}$	Maximum Working Peak Reverse Voltage		
$I_F(AV)$	Maximum Average Forward Current ( $T_C = 123^\circ\text{C}$ , Duty Cycle = 0.5)	75	Amps
$I_F(RMS)$	RMS Forward Current (Square wave, 50% duty)	208	
$I_{FSM}$	Non-Repetitive Forward Surge Current ( $T_J = 45^\circ\text{C}$ , 8.3ms)	600	
$T_J, T_{STG}$	Operating and Storage Temperature Range	-55 to 150	$^\circ\text{C}$
$T_L$	Lead Temperature for 10 Sec.	300	
$E_{VAL}$	Avalanche Energy (2A, 30mH)	60	

### STATIC ELECTRICAL CHARACTERISTICS

Symbol		MIN	TYP	MAX	UNIT
$V_F$	Forward Voltage	$I_F = 60\text{A}$	.83	.90	Volts
		$I_F = 120\text{A}$	.98		
		$I_F = 60\text{A}, T_J = 125^\circ\text{C}$	.72		
$I_{RM}$	Maximum Reverse Leakage Current	$V_R = V_R \text{ Rated}$		1	mA
		$V_R = V_R \text{ Rated}, T_J = 125^\circ\text{C}$		25	
$C_T$	Junction Capacitance, $V_R = 200\text{V}$		300		pF

### DYNAMIC CHARACTERISTICS

APT60S20B2CT

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
$t_{rr}$	Reverse Recovery Time	$I_F = 60A, di_F/dt = -200A/\mu s$ $V_R = 133V, T_C = 25^\circ C$	-	55		ns
$Q_{rr}$	Reverse Recovery Charge		-	160		nC
$I_{RRM}$	Maximum Reverse Recovery Current		-	5	-	Amps
$t_{rr}$	Reverse Recovery Time	$I_F = 60A, di_F/dt = -200A/\mu s$ $V_R = 133V, T_C = 125^\circ C$	-	100		ns
$Q_{rr}$	Reverse Recovery Charge		-	490		nC
$I_{RRM}$	Maximum Reverse Recovery Current		-	10	-	Amps
$t_{rr}$	Reverse Recovery Time	$I_F = 60A, di_F/dt = -700A/\mu s$ $V_R = 133V, T_C = 125^\circ C$	-	80		ns
$Q_{rr}$	Reverse Recovery Charge		-	1100		nC
$I_{RRM}$	Maximum Reverse Recovery Current		-	27		Amps

### THERMAL AND MECHANICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-Case Thermal Resistance			.30	$^\circ C/W$
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance			40	
$W_T$	Package Weight		0.22		oz
			5.9		g

APT Reserves the right to change, without notice, the specifications and information contained herein.

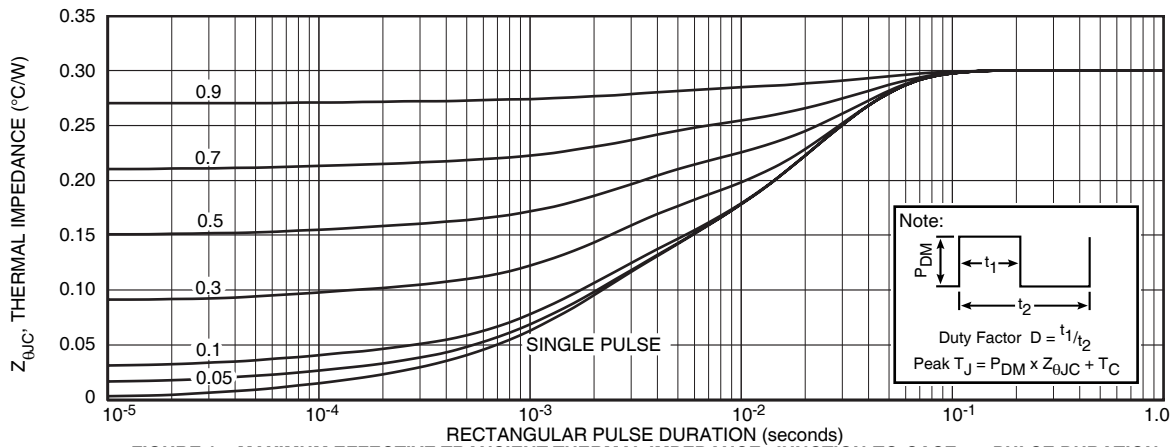


FIGURE 1a. MAXIMUM EFFECTIVE TRANSIENT THERMAL IMPEDANCE, JUNCTION-TO-CASE vs. PULSE DURATION

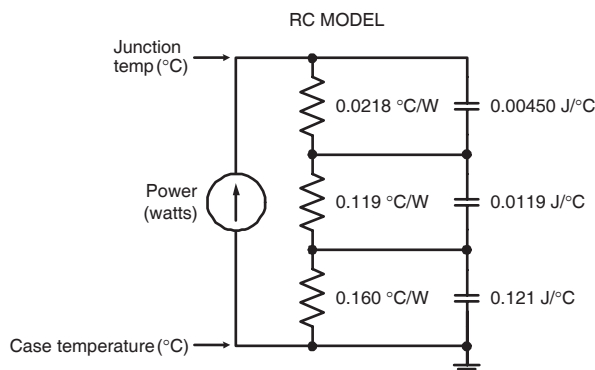


FIGURE 1b. TRANSIENT THERMAL IMPEDANCE MODEL

# TYPICAL PERFORMANCE CURVES

APT60S20B2CT

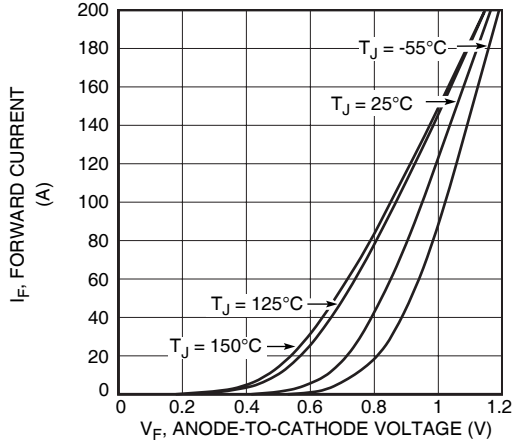


Figure 2. Forward Current vs. Forward Voltage

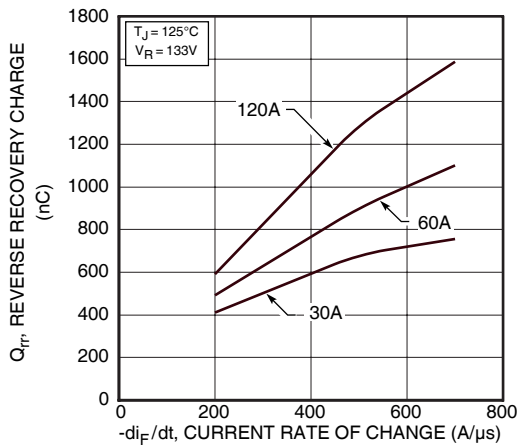


Figure 4. Reverse Recovery Charge vs. Current Rate of Change

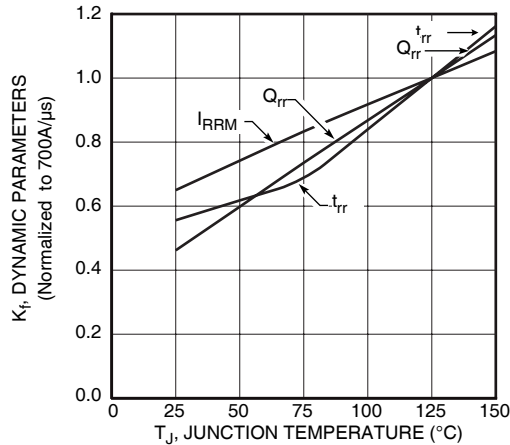


Figure 6. Dynamic Parameters vs. Junction Temperature

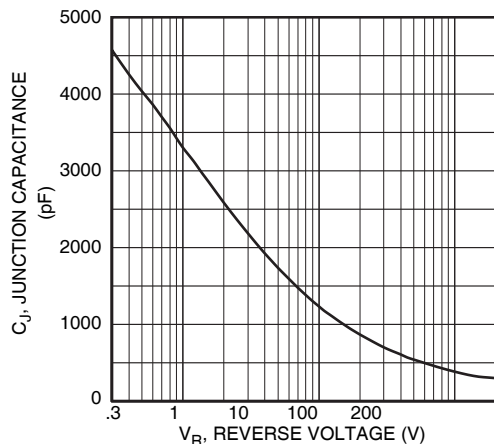


Figure 8. Junction Capacitance vs. Reverse Voltage

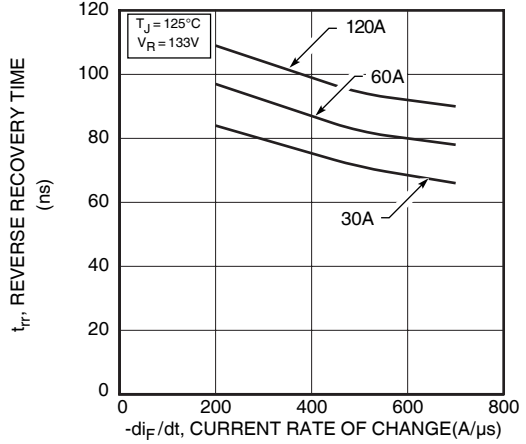


Figure 3. Reverse Recovery Time vs. Current Rate of Change

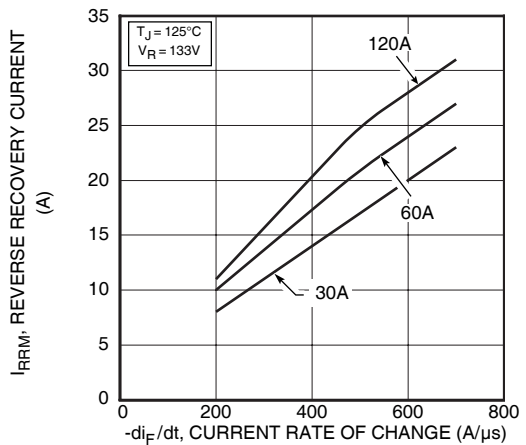


Figure 5. Reverse Recovery Current vs. Current Rate of Change

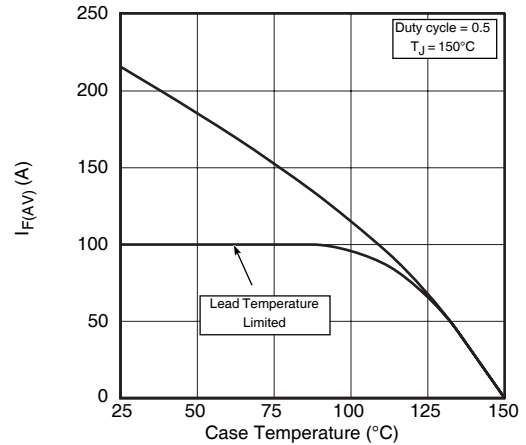


Figure 7. Maximum Average Forward Current vs. Case Temperature

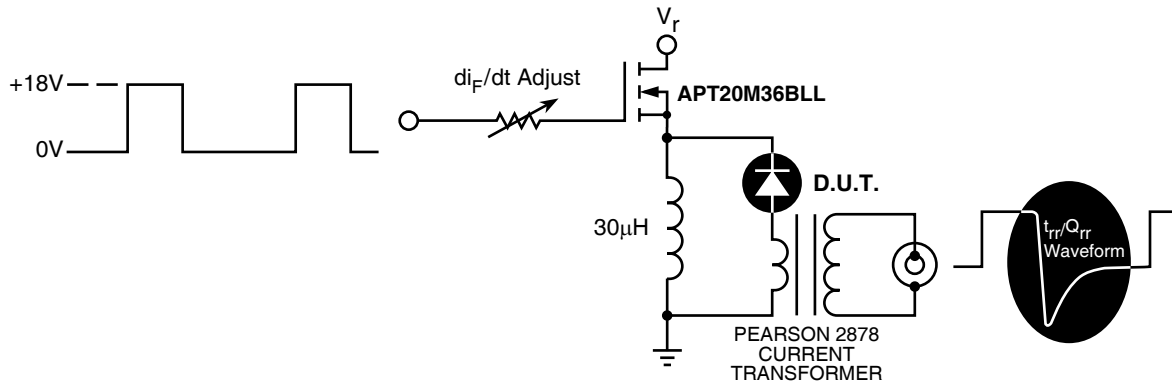


Figure 9. Diode Test Circuit

- 1  $I_F$  - Forward Conduction Current
- 2  $di_F/dt$  - Rate of Diode Current Change Through Zero Crossing.
- 3  $I_{RRM}$  - Maximum Reverse Recovery Current.
- 4  $t_{rr}$  - Reverse Recovery Time, measured from zero crossing where diode current goes from positive to negative, to the point at which the straight line through  $I_{RRM}$  and  $0.25 \cdot I_{RRM}$  passes through zero.
- 5  $Q_{rr}$  - Area Under the Curve Defined by  $I_{RRM}$  and  $t_{rr}$ .

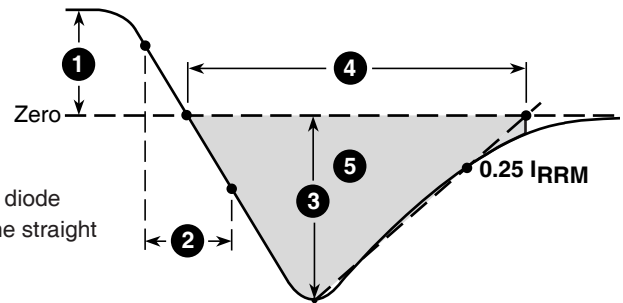
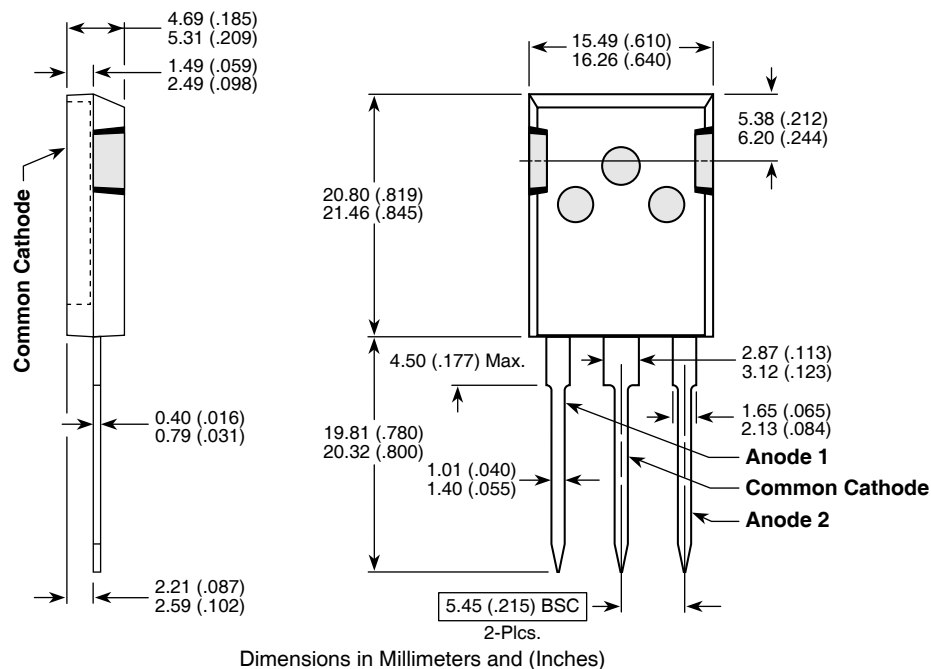


Figure 10, Diode Reverse Recovery Waveform and Definitions

### T-MAX™ (B2) Package Outline



Dimensions in Millimeters and (Inches)